Thyristor Semiconductor Device - Page 1 of 1



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nclosure Material:
Vetal
Overall Length:
1.310 inches
Overall Diameter:
5.063 inches
Mounting Facility Quantity:
1
nternal Configuration:
Junction contact
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Thread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 breakover voltage, dc
Current Rating Per Characteristic:
400.00 amperes source cutoff current
Power Rating Per Characteristic:
16.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Thread Series Designator:
Jnf
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
30131-release4911 professional/industrial association specification
Shelf Life:
v/a
Unit Of Measure:
-
Demilitarization:
No
Fiig: